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I hereby certify that this correspondence is being hand delivered to:
Commissioner for Patents, 2011 South Clark Place, Room 1B03, Crystal
Plaza 2, Arlington, Virginia, 22202, on the date shown below.
Dated: 7/30/03 Signature: Nancy DeRaggi
(Nancy DeRaggi)

Docket No.: 204552016500
(PATENT)



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Patent Application of:
Yuichi SATO

Application No.: 09/412,328

Group Art Unit: 2814

Filed: October 5, 1999

Examiner: D. Wille

For: STATIC RANDOM ACCESS MEMORY AND
SEMICONDUCTOR DEVICE USING MOS
TRANSISTORS HAVING CHANNEL REGION
ELECTRICALLY CONNECTED WITH GATE

SUPPLEMENTAL AMENDMENT UNDER 37 CFR 1.111

Mail Stop Non-Fee Amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

In response to the Office Action dated April 3, 2003 and supplemental to the Amendment Under 37 CFR 1.111 filed July 3, 2003, please amend the above-identified U.S. patent application as follows:

Amendments to the Claims are reflected in the listing of claims which begins on page 2 of this paper.

Remarks begin on page 4 of this paper.